



L Number	Hits	Search Text	DB	Time stamp
2	244	((insulating or dielectric) same (etch\$3	USPAT;	2003/04/18
2	211	or remov\$3) same (C4F8 or	EPO; JPO;	07:17
		"C.sub.4F.sub.8" or C5F8 or	IBM TDB	
		"C.sub.5F.sub.8" or fluorocarbons)) and	1201_122	
		("etch stop" or SiN or "silicon nitride")		1
		and (trench or via or "contact hole")	1	
	2	(etch\$3 or remov\$3) same ((C4F8 or	USPAT;	2003/04/18
4	2	"C.sub.4F.sub.8") same (C5F8 or	EPO; JPO;	09:41
			IBM TDB	09.41
		"C.sub.5F.sub.8"))		2002/04/19
6	3	(C4F8 or "C.sub.4F.sub.8" or	USPAT;	2003/04/18
		octafluorocyclobutane) with (C5F8 or	EPO; JPO;	08:23
		"C.sub.5F.sub.8" or	IBM_TDB	
		octafluorocyclopentence)		2002/04/10
1	592	(insulating or dielectric) same (etch\$3	USPAT;	2003/04/18
		or remov\$3) same (C4F8 or	EPO; JPO;	10:45
		"C.sub.4F.sub.8" or C5F8 or	IBM_TDB	
		"C.sub.5F.sub.8" or fluorocarbons)		1
12	17	(etch\$3 or remov\$3) same (C5F8 or	USPAT;	2003/04/18
		"C.sub.5F.sub.8")	EPO; JPO;	09:51
			IBM_TDB	}
15	19	(etch\$3 or remov\$3) and (C5F8 or	USPAT;	2003/04/18
		"C.sub.5F.sub.8")	EPO; JPO;	09:56
		,	IBM TDB	1
16	1	5338399.pn.	USPAT;	2003/04/18
	-	0330333.p.m.	EPO; JPO;	10:20
			IBM TDB	
17	20	((insulating or dielectric) same (etch\$3	USPAT;	2003/04/18
	2.0	or remov\$3) same (C4F8 or	EPO; JPO;	10:20
		"C.sub.4F.sub.8" or C5F8 or	IBM TDB	10.20
ļ		"C.sub.5F.sub.8" or fluorocarbons)) and	1511_155	
ļ				
18	0.7	"partial pressure"	USPAT;	2003/04/18
	87	(insulating or dielectric) same (etch\$3	EPO; JPO;	11:07
		or remov\$3) same (C4F8 or		11:07
		"C.sub.4F.sub.8" or C5F8 or	IBM_TDB	
		"C.sub.5F.sub.8" or fluorocarbons) same		
		(plug or copper or Cu or wiring)	[00000101110
19	3066	(insulating or dielectric) and (etch\$3	USPAT;	2003/04/18
ļ		or remov\$3) and (C4F8 or "C.sub.4F.sub.8"	EPO; JPO;	11:09
j		or C5F8 or "C.sub.5F.sub.8" or	IBM_TDB	1
		fluorocarbons) and (plug or copper or Cu	Į.	
		or wiring)		
20	726	((insulating or dielectric) and (etch\$3	USPAT;	2003/04/18
		or remov\$3) and (C4F8 or "C.sub.4F.sub.8"	EPO; JPO;	11:09
		or C5F8 or "C.sub.5F.sub.8" or	IBM_TDB	
		fluorocarbons) and (plug or copper or Cu	_	
		or wiring)) and (selective or		
		selevtivity)		1
21	226	(((insulating or dielectric) and (etch\$3	USPAT;	2003/04/18
21	220	or remov\$3) and (C4F8 or "C.sub.4F.sub.8"	EPO; JPO;	11:10
		or C5F8 or "C.sub.5F.sub.8" or	IBM TDB	
1		fluorocarbons) and (plug or copper or Cu		
1		or wiring)) and (selective or	1	
}			1	
22	0100	selevtivity)) and 438/\$.ccls.	HCDAT.	2003/04/18
22	2108	((438/706) or (438/710) or (438/712) or	USPAT;	1 ' '
		(438/720)).CCLS.	EPO; JPO;	11:10
			IBM_TDB	2002/04/12
23	96	(((438/706) or (438/710) or (438/712) or	USPAT;	2003/04/18
		(438/720)).CCLS.) and ((insulating or	EPO; JPO;	11:10
		dielectric) and (etch\$3 or remov\$3) and	IBM_TDB	
		(C4F8 or "C.sub.4F.sub.8" or C5F8 or		
		"C.sub.5F.sub.8" or fluorocarbons) and	1	
		(plug or copper or Cu or wiring))		